Erratum to "A 66 μW 86 ppm/°C Fully-Integrated 6 MHz Wienbridge Oscillator With a 172 dB Phase Noise FOM"

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In the above paper [1], Table II compares the phase noise behavior of the Wienbridge oscillator with other work. While this work uses W(att) in the FOM formula (2), the authors of [2] and [3] have used the more common definition with the power normalized to mW (1), [4]. Unfortunately, due to this mistake, the figure of merit (FOM) of [2] and [3] was underestimated by 30 dB. Table II is reprinted with the corrected FOM values (FOM_2), (2). An extra column is added where the more common definition (1) is used (FOM).

$$\mathrm{FOM} = 10 \cdot log\left(\frac{f_{\mathrm{osc}}^2}{f_m^2 \cdot L(f_m)} \cdot \frac{1}{P_{\mathrm{diss}}[mW]}\right) \tag{1}$$

$$\mathrm{FOM}_2 = 10 \cdot log\left(\frac{f_{\mathrm{osc}}^2}{f_m^2 \cdot L(f_m)} \cdot \frac{1}{P_{\mathrm{diss}}[W]}\right). \tag{2}$$

The authors regret their mistake. The authors would also like to take the opportunity to correct some typos in the reference list. References [19] and [24] of the original manuscript should be [5] and [11] of this erratum.

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TABLE I
COMPARISON TO THE STATE-OF-THE-ART

Ref.	Type	Tech.	f (*MHz*)	T Sens. (ppm/°*C*)	P	FOM_2 (*dB*)	FOM (*dB*)	Trimming/Calibration?
This Work	RC	65 *nm*	6	86	66 μW	172 (180)	142 (150)	No
[5]	LC	0.35 μm	12	12	31 mW	180	150	No
[6]	relaxation	0.5 μm	4 – 22	460	400 μW			Yes
[7]	ring	0.6 μm	0.68	106	400 μW			No
[8]	ring	0.25 μm	7	400	1.5 mW			No
[2]	relaxation	65 *nm*	12		90 μW	191	161	No
[3]	relaxation	0.8 μm	1.5		1.8 mW	180,7	150,7	No
[9]	relaxation	1.2 μm	148	1000	1.1 mW	176	146	No
[10]	relaxation	65 *nm*	0.1	103	41.2 μW			Ext. Ref.
[11]	relaxation	0.13 μm	2	375	3 μW	169,7	139,7	Yes

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